



Microdosimetry for ion-beam therapy at EBG MedAustron

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Detectors and methodology

—● Diamond Detector

- Detector prototypes
- Zagreb microbeam: Ion-Beam Induced Charge, IBIC
- Proton microdosimetry

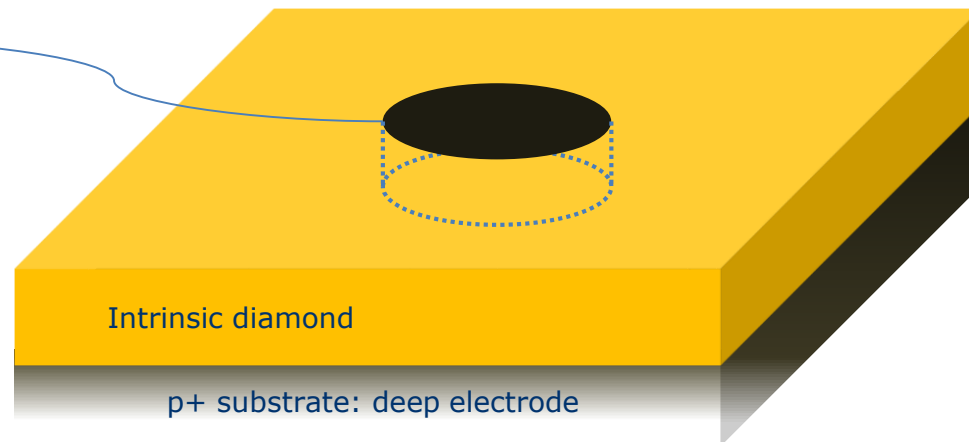
—● Common solid state transversal characteristic

"Suboptimal" definition of the sensitive volume

Prototype version 0

- The substrate is an (extended) electrode
- Definition of the cross section of the sensitive volume through the shape of the metallic contact on top of the diamond
- Built in potential
- Need of a small cross section to be capable of working with high beam intensities

To the electronics



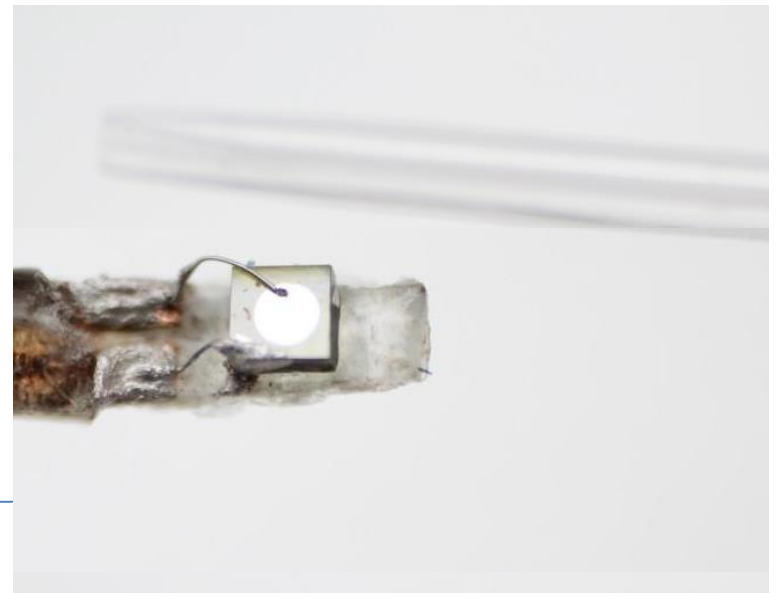
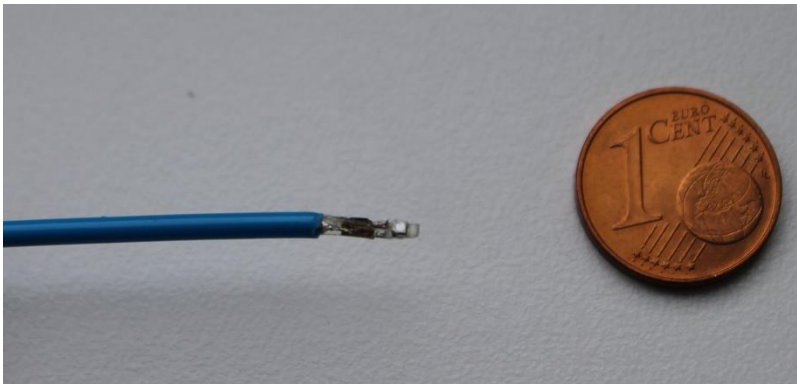
Collaboration with
U. Tor Vergata, Rome:

C. Verona, G. Magrin, P. Solevi, M. Bandorf, M. Marinelli, M. Stock, G. Verona Rinati, Toward the use of single crystal diamond based detector for ion-beam therapy microdosimetry, Radiation Measurements, 110 (2018) 25-31

Reduced size of the detector

MicroDiamonds

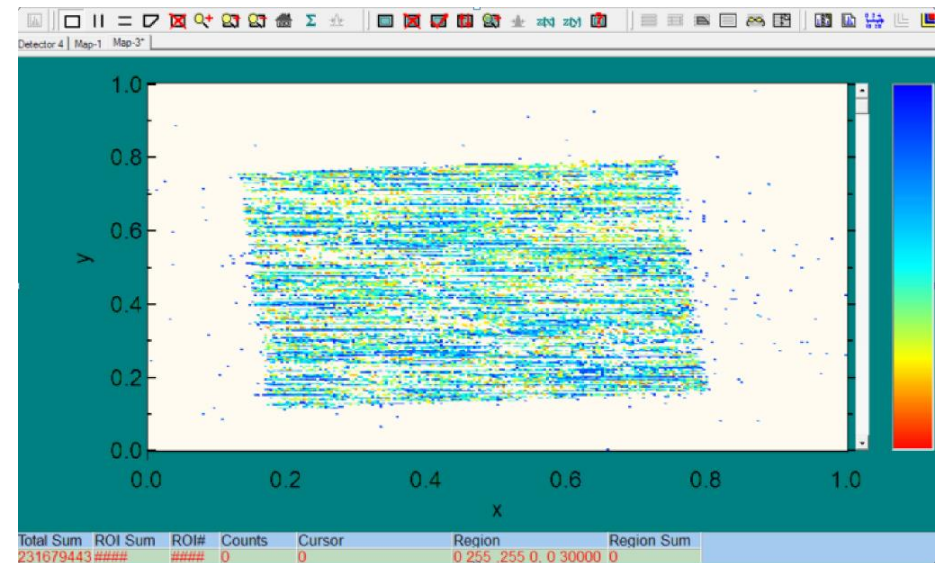
- Nominal thicknesses of sensitive volume: from 0.25 μm to 5 μm
- Diameter of sensitive cross area: 100 μm , 2000 μm
- Overall volume of the order of 1 mm^3



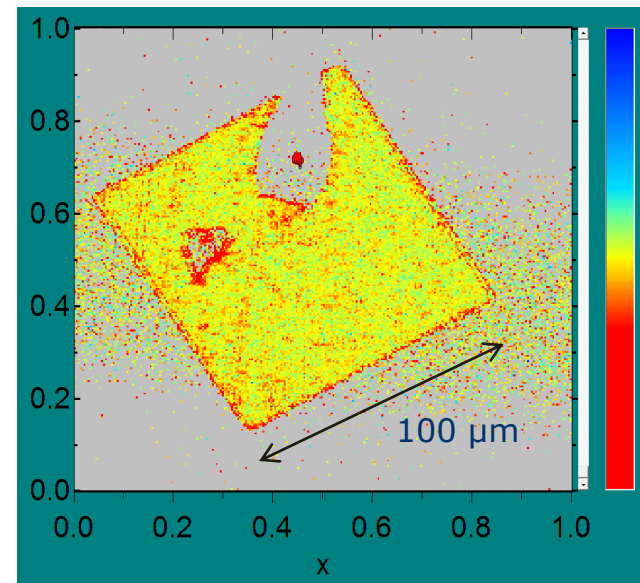
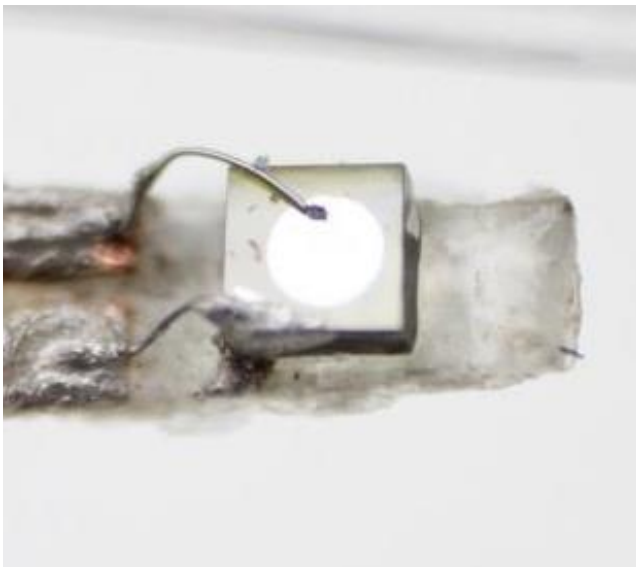
Distorsion of the definition of the sensitive volume

Microbeam test IBIC

- Single particles (5 MeV silicon ions in the example) are scanned toward the sample
- The uncertainty in the beam position order of $1\mu\text{m}$.
- The detector is operative and perpendicular to the beam direction. When the particle passes through the sensitive area the ionization is registered.
- The synchronization between of the signal and the scanning of the beam provide the transversal position
- The process is repeated several times



Building a clear sensitive volume



The welding material on top of the metallic contact is thick enough to stop the alpha particles which do not reach the sensitive area.

Improving the prototypes

Prototype version 1

- Aluminium oxide (Al_2O_3) is grown on the side of the metallic contact to create a region non-sensitive to radiation where to weld the wire
- The dielectric constant of the oxide is approximately twice that of the diamond
- The thickness of the oxide cannot exceed 1 or 2 μm : cracks
- A secondary peak (red in figure 2) appears

To the electronics

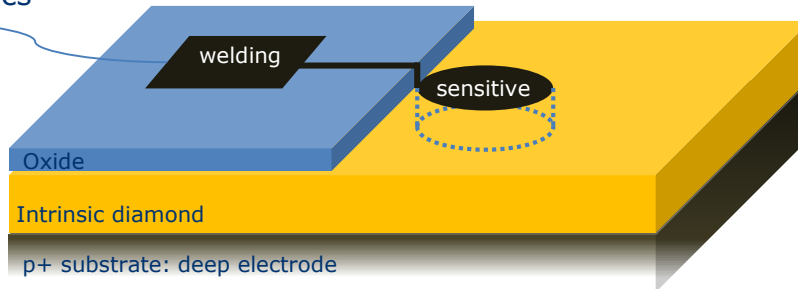


Figure 1.

The welding of the external wire is on the

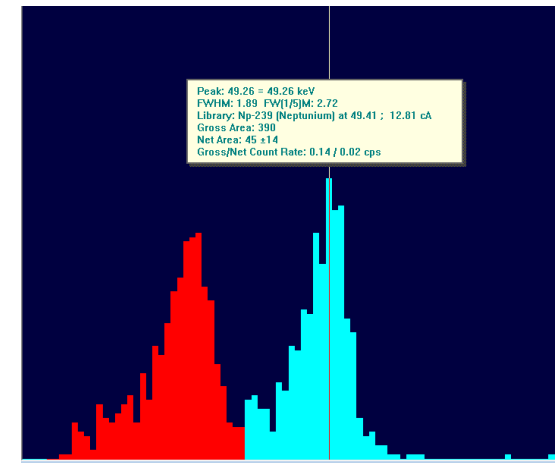


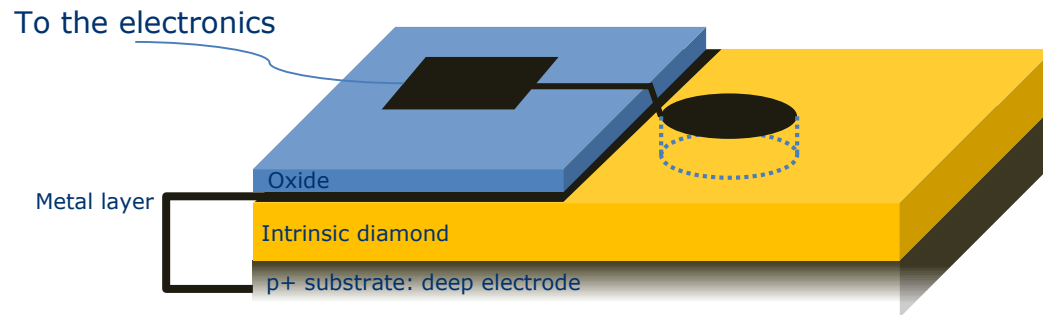
Figure 2.

A second peak at low channels is visible when 6V are supplied. Am-241 alpha source. 2 μm thick diamond.

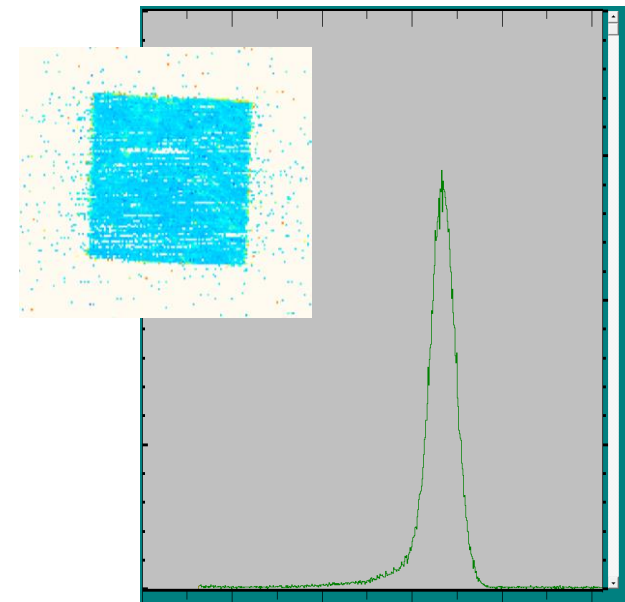
Improving the prototypes

Prototype version 2

- A metal layer is deposited on the intrinsic diamond before growing the aluminium oxide and it is electrically connected to the substrate (**figure**). The region between the two has zero voltage and therefore the ions produced by the irradiation do not contribute to the pulse.
- No secondary peaks are visible.



The welding of the external wire is on the



A single peak.
Lithium 14.46 MeV. 2µm thick diamond

Improving the prototypes

Prototype version 3

- The purpose is to shape also the p+ substrate to the same shape of the metal contact. The electric field is created by two electrodes of the same shape
- The intrinsic diamond extends outside the region of the

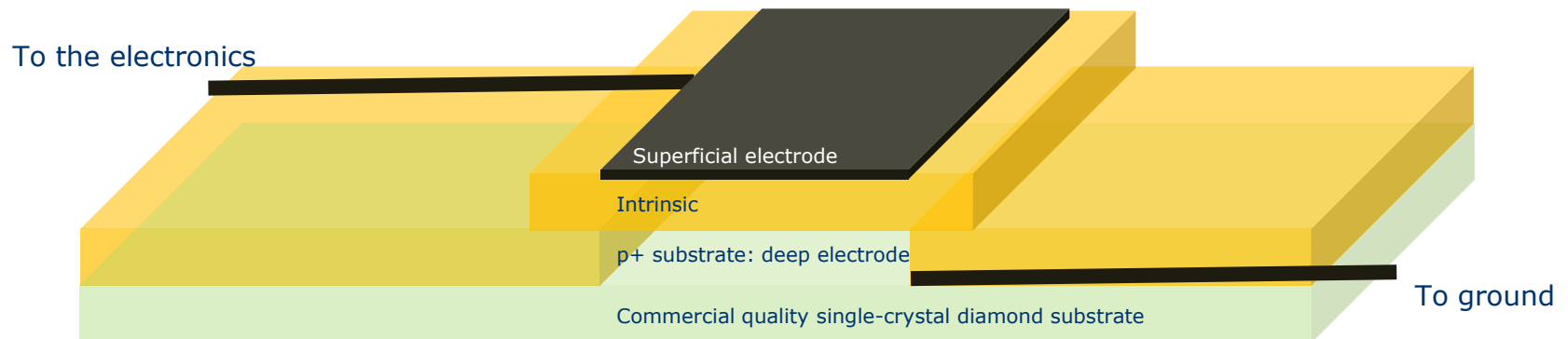
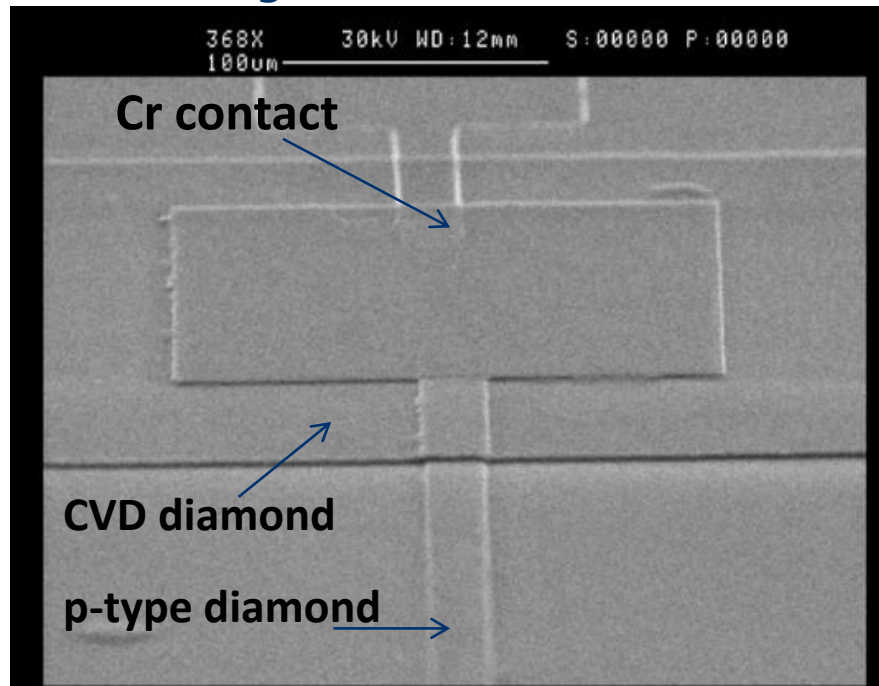


Figure.

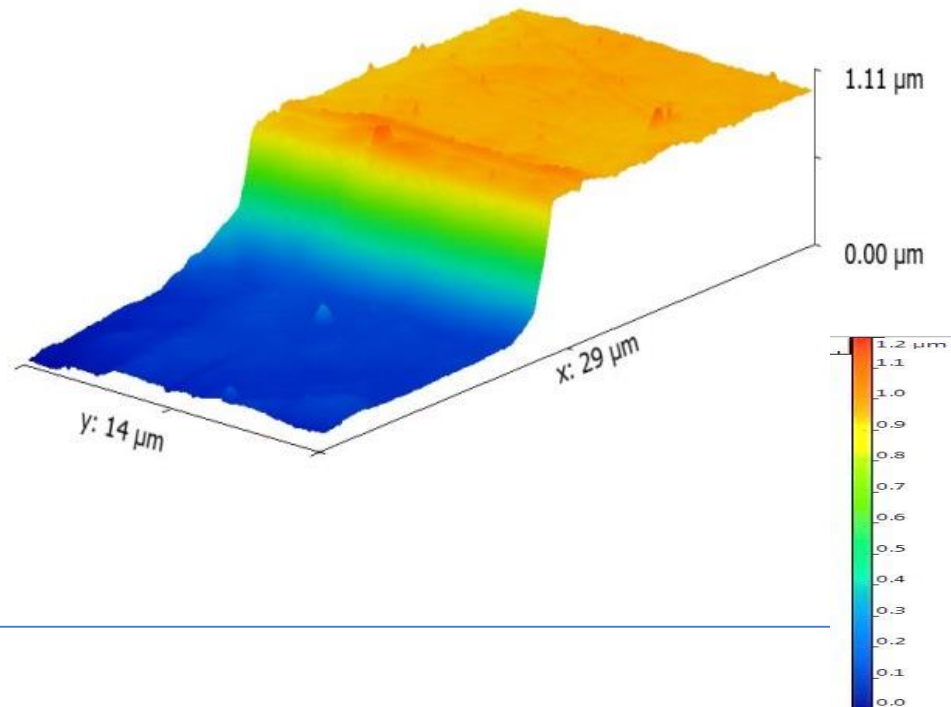
The latest configuration. The sensitive volume is straightly defined between the superficial metal contact and the p+ substrate

Microscopic imaging

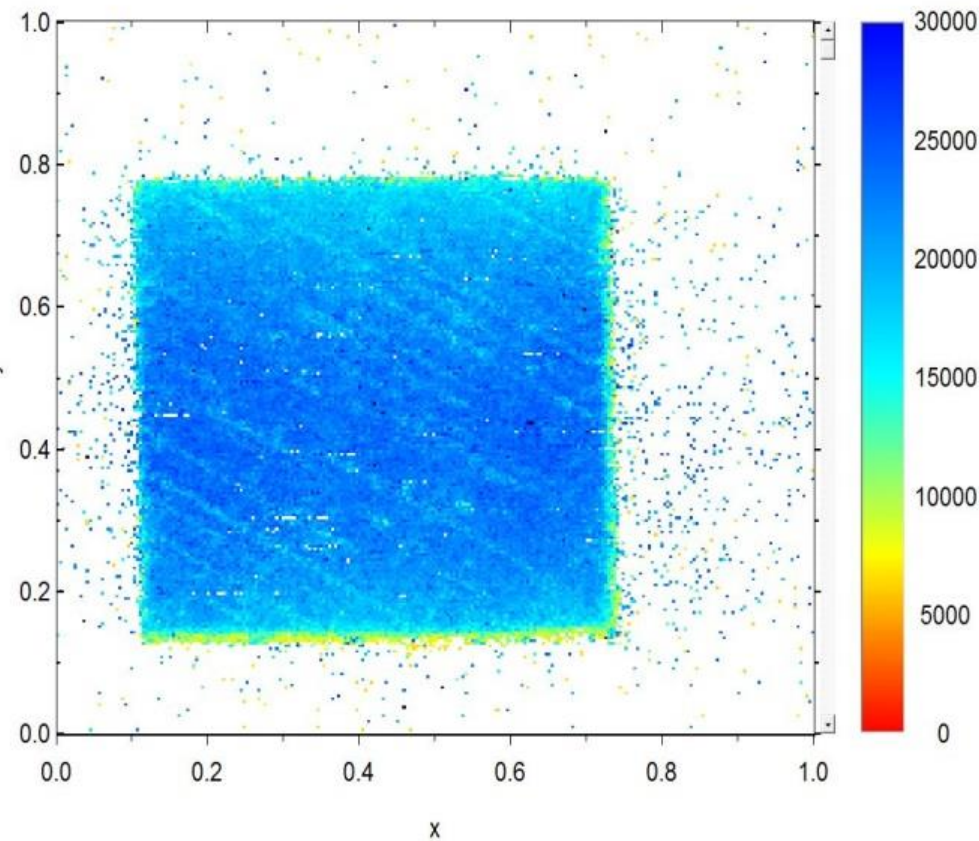
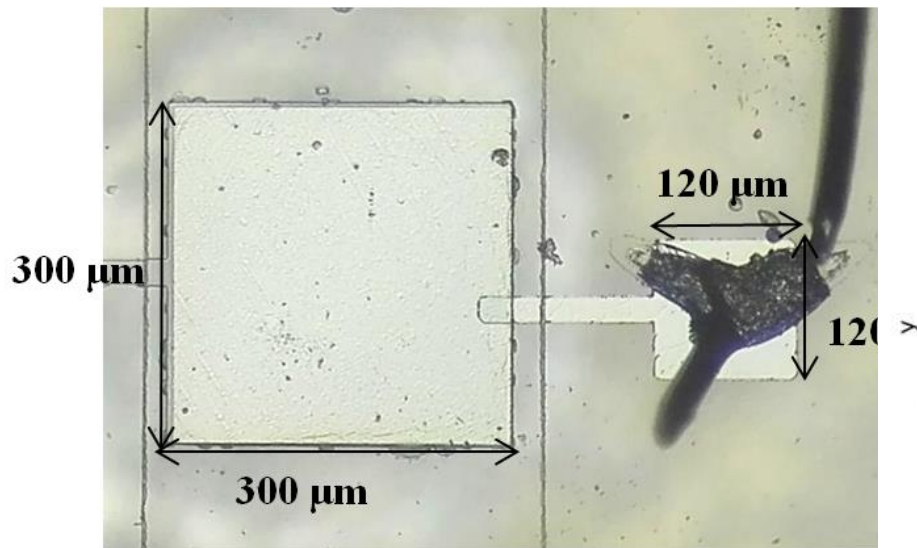
Scanning Electron Microscope
image of the diamond



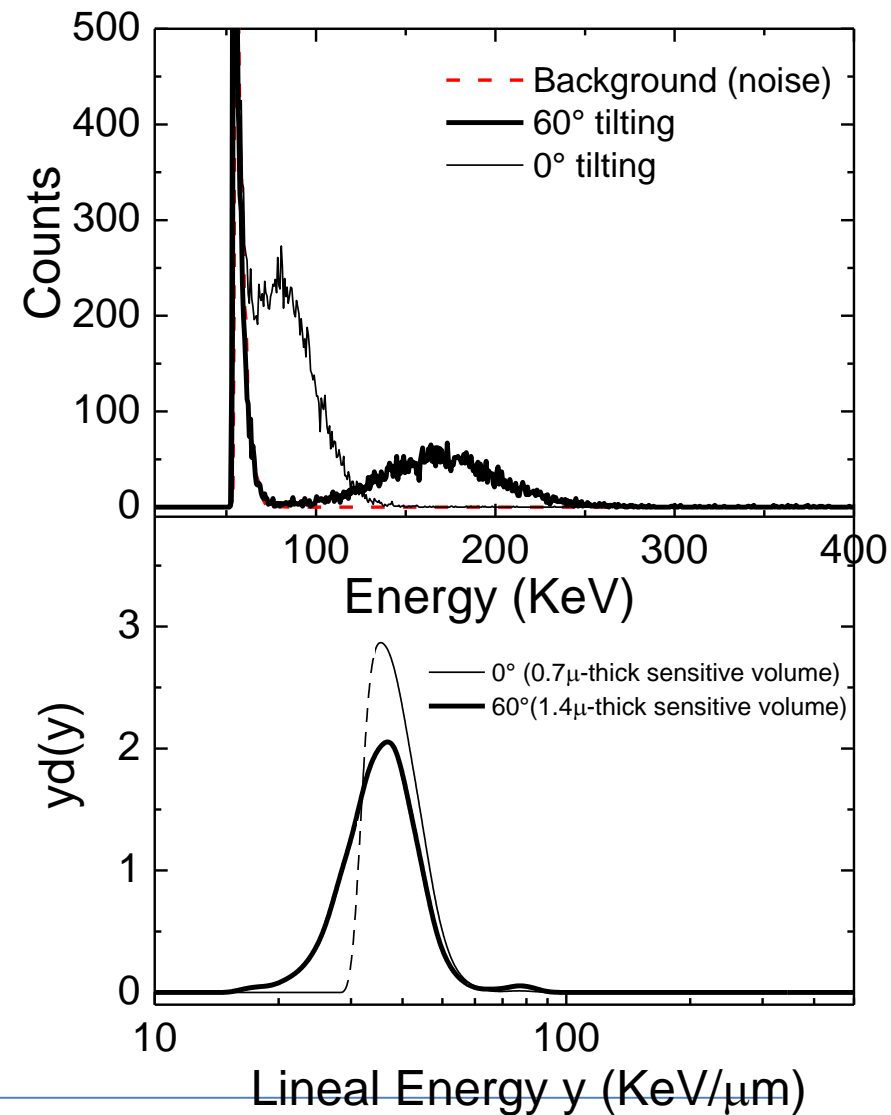
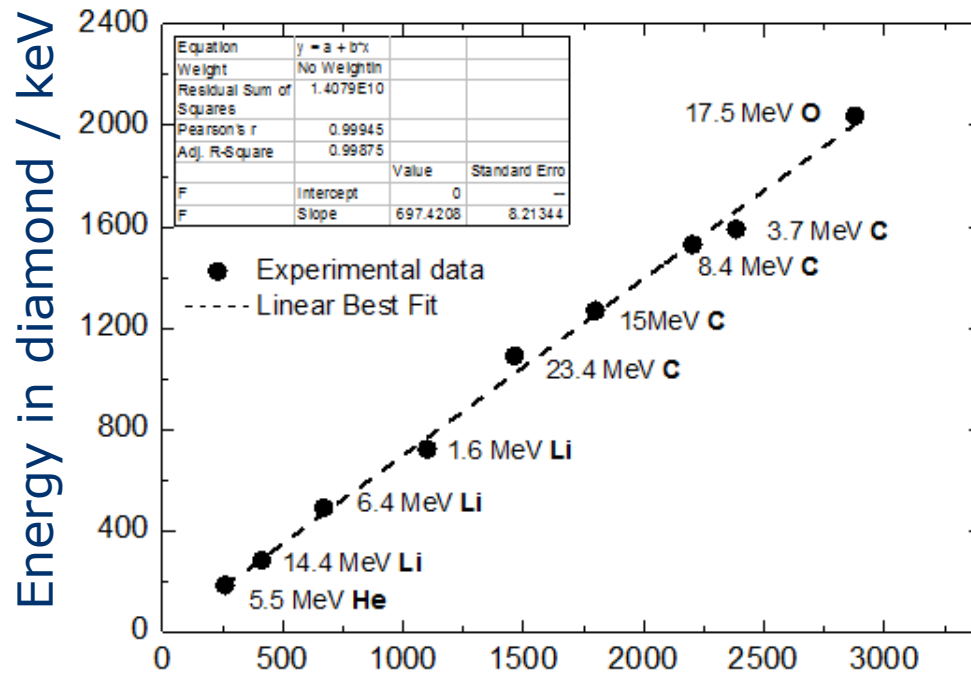
Atomic force microscopy image of
intrinsic diamond growth



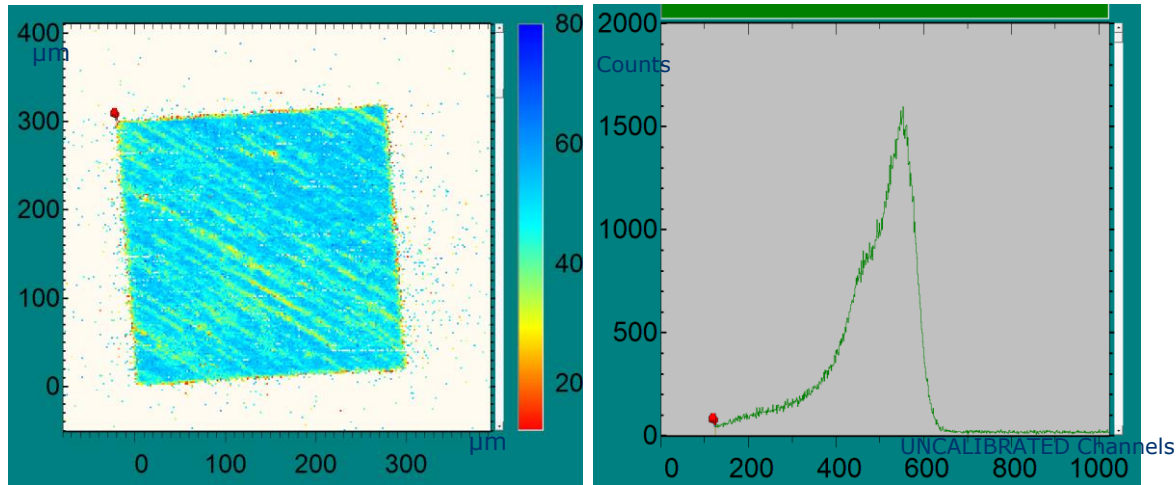
Realization of the prototype 3.0



Tests with 10 different radiation qualities

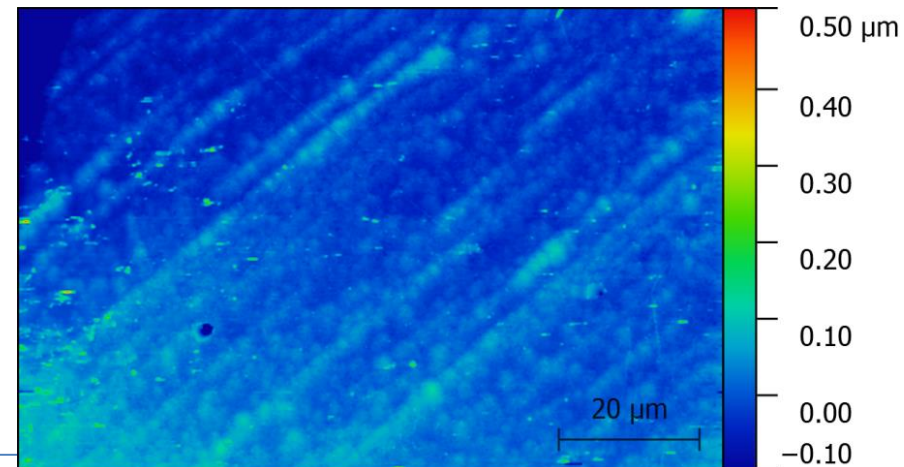


Electron stopping power / keV·μm⁻¹



Ion Beam Induced Charge tests of carbon ions (15 MeV) in diamond detectors. The map (left) shows distortions of reading in the detector areas. The peak (ideally a thin Gaussian) enlarged and distorted.

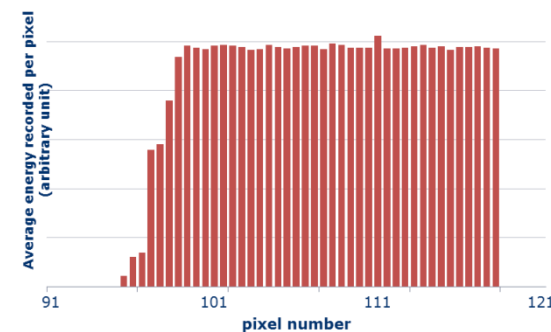
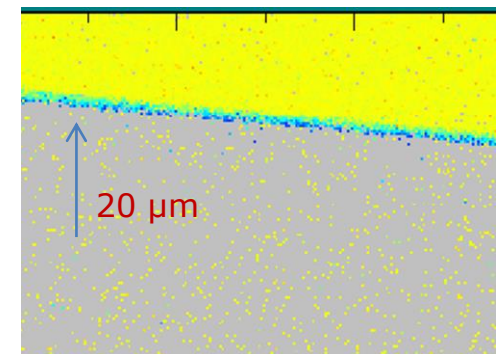
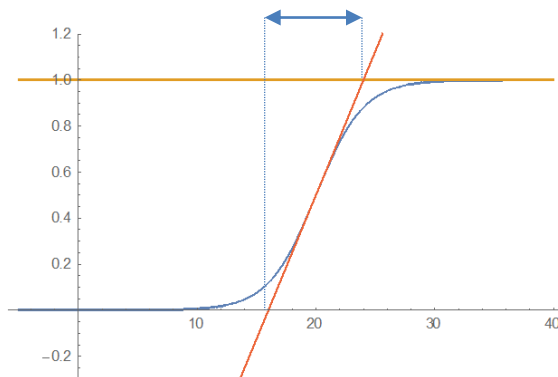
Atomic force microscopy image (70 μm x 100 μm)



Transversal characteristic in solid state detectors: borders

- Resolution of the system given by the unknown "beam size" (of the order of 3-4 μm)
- Extract of a pixel line: Transition in pixel response between homogeneous area and undetectable response
- Sigmoid interpolation

Zoom-in IBIC

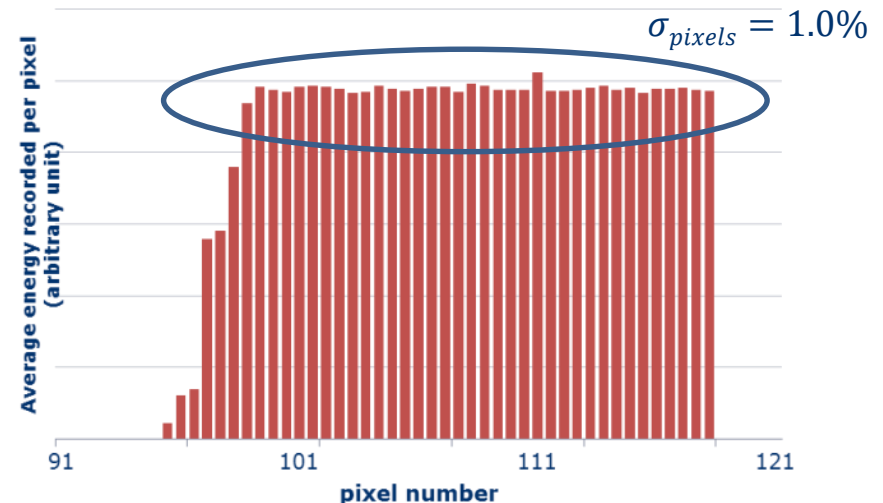


- with C-ion 15 MeV, the border $\leq 3.33 \pm 0.71 \mu\text{m}$

Transversal characteristic in solid state detectors: uniformity

Uniformity studies

- Total fluctuations depend on pulse height fluctuations, the number of particles per pixel, and **non-uniformity of the local response**.



- Rescan the same pixels with different ion probes to see correlations of the response: very challenging because of the time dependence of IBIC test